

# Seungjin Lee

## List of Publications by Year in descending order

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21  
papers

1,374  
citations

516710

16  
h-index

677142

22  
g-index

22  
all docs

22  
docs citations

22  
times ranked

2397  
citing authors

#	ARTICLE	IF	CITATIONS
1	Boosting the efficiency of quasi-2D perovskites light-emitting diodes by using encapsulation growth method. <i>Nano Energy</i> , 2021, 80, 105511.	16.0	54
2	Molecular aggregation method for perovskite/fullerene bulk heterostructure solar cells. <i>Journal of Materials Chemistry A</i> , 2020, 8, 1326-1334.	10.3	15
3	Water-stable polymer hole transport layer in organic and perovskite light-emitting diodes. <i>Journal of Power Sources</i> , 2020, 478, 228810.	7.8	6
4	Sky-Blue-Emissive Perovskite Light-Emitting Diodes: Crystal Growth and Interfacial Control Using Conjugated Polyelectrolytes as a Hole-Transporting Layer. <i>ACS Nano</i> , 2020, 14, 13246-13255.	14.6	38
5	A-Site Cation Engineering for Efficient Blue-Emissive Perovskite Light-Emitting Diodes. <i>Energies</i> , 2020, 13, 6689.	3.1	5
6	Solution processable small molecules as efficient electron transport layers in organic optoelectronic devices. <i>Journal of Materials Chemistry A</i> , 2020, 8, 13501-13508.	10.3	19
7	Uniform and Large-Area Cesium-Based Quasi-2D Perovskite Light-Emitting Diodes Using Hot-Casting Method. <i>Advanced Materials Interfaces</i> , 2020, 7, 1902158.	3.7	25
8	Highly Efficient Flexible Perovskite Light-Emitting Diodes Using the Modified PEDOT:PSS Hole Transport Layer and Polymer-Silver Nanowire Composite Electrode. <i>ACS Applied Materials &amp; Interfaces</i> , 2019, 11, 39274-39282.	8.0	24
9	Versatile Defect Passivation Methods for Metal Halide Perovskite Materials and their Application to Light-Emitting Devices. <i>Advanced Materials</i> , 2019, 31, e1805244.	21.0	92
10	Conjugated Polyelectrolytes as Multifunctional Passivating and Hole-Transporting Layers for Efficient Perovskite Light-Emitting Diodes. <i>Advanced Materials</i> , 2019, 31, e1900067.	21.0	44
11	Flexibility of Semitransparent Perovskite Light-Emitting Diodes Investigated by Tensile Properties of the Perovskite Layer. <i>Nano Letters</i> , 2019, 19, 971-976.	9.1	37
12	Conjugated Polyelectrolytes Bearing Various Ion Densities: Spontaneous Dipole Generation, Poling-Induced Dipole Alignment, and Interfacial Energy Barrier Control for Optoelectronic Device Applications. <i>Advanced Materials</i> , 2018, 30, e1706034.	21.0	12
13	Growth of Nanosized Single Crystals for Efficient Perovskite Light-Emitting Diodes. <i>ACS Nano</i> , 2018, 12, 3417-3423.	14.6	109
14	Control of Interface Defects for Efficient and Stable Quasi-2D Perovskite Light-Emitting Diodes Using Nickel Oxide Hole Injection Layer. <i>Advanced Science</i> , 2018, 5, 1801350.	11.2	92
15	Conjugated Polyelectrolytes as Efficient Hole Transport Layers in Perovskite Light-Emitting Diodes. <i>ACS Nano</i> , 2018, 12, 5826-5833.	14.6	56
16	Amine-Based Passivating Materials for Enhanced Optical Properties and Performance of Organic-Inorganic Perovskites in Light-Emitting Diodes. <i>Journal of Physical Chemistry Letters</i> , 2017, 8, 1784-1792.	4.6	220
17	Improved performance of perovskite light-emitting diodes using a PEDOT:PSS and MoO <sub>3</sub> composite layer. <i>Journal of Materials Chemistry C</i> , 2016, 4, 8161-8165.	5.5	75
18	Amine-Based Interfacial Molecules for Inverted Polymer-Based Optoelectronic Devices. <i>Advanced Materials</i> , 2015, 27, 3553-3559.	21.0	77

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19	High-Performance Planar Perovskite Optoelectronic Devices: A Morphological and Interfacial Control by Polar Solvent Treatment. <i>Advanced Materials</i> , 2015, 27, 3492-3500.	21.0	205
20	Amine-Based Polar Solvent Treatment for Highly Efficient Inverted Polymer Solar Cells. <i>Advanced Materials</i> , 2014, 26, 494-500.	21.0	159
21	Combination effect of polar solvent treatment on ZnO and polyfluorene-based polymer blends for highly efficient blue-based hybrid organic-inorganic polymer light-emitting diodes. <i>Journal of Materials Chemistry C</i> , 2014, 2, 8673-8677.	5.5	8